Ferromagnetic ' π '-junctions

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We investigate Josephson coupling through a ferromagnetic thin film using Superconductor-Insulator-Ferromagnet-Superconductor planar junctions. Damped oscillations of the critical current are observed as a function of the ferromagnetic layer thickness. We show that they result from the exchange energy gained or lost by a quasiparticle Andreev-reflected at the ferromagnet-superconductor interface. The critical current cancels out at the transition from positive ("0") to negative (" π ") coupling, in agreement with theoretical calculations.

Current can flow without dissipation through a thin insulating layer or a weak link separating two superconductors. Because of the quantum character of the superflow a phase difference, θ , between the superconductors appears. The current-phase relationship of the link is a periodic function of θ . For a tunnel barrier, as first found by Josephson, [1] it is given by $I = I_c \sin(\theta)$, where I_c is the critical current. In this Letter, we show that I_c can change sign when the superconductors are coupled via a thin ferromagnetic layer. Referring to the Josephson current-phase relationship, this change corresponds to a π -phase shift of θ . Thus Josephson junctions presenting a negative coupling are usually called π -junctions. We specifically observe the transition from a positive to a negative coupling or equivalently from "0" to " π " junctions by increasing the ferromagnetic layer thickness.

The possibility of a negative Josephson coupling was first raised by Kulik [2]. It is due to the spin-flip of the electrons forming a Cooper pair when tunneling through an insulator. The spin-flip originates from the electron exchange interaction with uncorrelated magnetic impurities in the barrier. This channel, which coexists with direct tunneling, is suggested to reduce the critical current of the junction. Whether or not spin-flip tunneling can overtake direct tunneling, leading to a negative critical current, remains uncertain.

More recently Buzdin et al. [3] showed that in ballistic Superconductor/Ferromagnet/Superconductor weak links (S/F/S), I_c displays damped oscillations as a function of d_F , the thickness of F. Close to the critical temperature of the superconductor an analytical expression of I_c is available. They found $I_c \propto \sin \phi_F/\phi_F$, where $\phi_F = 2E_{ex}d_F/\hbar v_F$. E_{ex} is the exchange energy and v_F the Fermi velocity in F. When ϕ_F is greater than π and smaller than 2π , I_c is negative leading to a π -coupling. Physically, this is a consequence of the phase change of the pair function induced in F by the proximity effect [4]. In fact, energy conservation requires that a Cooper pair entering into the ferromagnet receives a finite momentum, $\Delta p = \hbar v_F/2E_{ex}$, from the spin splitting of the up and down bands [5]. By quantum mechanics, Δp modifies the phase, $\phi = \Delta p \cdot x$, of the pair wave function that increases linearly with the distance, x, from the S/F interface. If all pair trajectories and spin configurations are

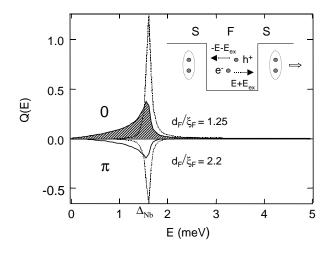


FIG. 1: Spectral current density, $Q(\epsilon)$, as a function of energy for SFS (full line) and SIFS (dashed line) Josephson junctions. $Q(\epsilon)$ is calculated from the Usadel equations 9 for two different d_F/ξ_F ratios. The "0" $(d_F/\xi_F=1.8)$ and " π " $(d_F/\xi_F=3)$ couplings result from positive (dashed area) and negative integrals respectively. The inset illustrates the transfer mechanism for Cooper pairs through F by Andreev reflections.

taken into account, the amplitude of the superconducting order parameter in F is given by $\sin(\phi)/\phi$ [5]. When F is coupled to a second superconductor through a weak link, the Josephson critical current is proportional to the pair amplitude in F and hence to $\sin \phi_F/\phi_F$.

Microscopically the transfer of Cooper pairs through the ferromagnet occurs via Andreev reflections [6]. An electron-like excitation in F with energy lower than the superconducting energy gap, Δ , cannot enter into the superconductor. It is reflected at the F/S interface as a hole and it is then reflected back as an electron at the opposite S/F interface as illustrated in the inset of Fig. 1 [7]. The constructive interference of the electron-like and hole-like excitations gives rise to Andreev bound states (ABS) in F, which carry the supercurrent. The same mechanism accounts for the Josephson coupling through a normal metal [7], but in a ferromagnet the spectrum of the ABS is affected by the spin splitting of the spin bands as the Andreev reflections reverse the spin of the quasiparticles [8]. Therefore the spectral current density, $Q(\epsilon)$

that defines the current density per bound state in F is a function of the exchange energy, E_{ex} . In the dirty limit, $Q(\epsilon)$ can be obtained by solving [9] the Usadel equations [10]. The exponential decay of the order parameter in F on a length scale given by $\xi_F = \sqrt{\hbar D/2E_{ex}}$, the coherence length in F, allows use of the "long junction" approximation [11], in which the thickness of the ferromagnetic layer, d_F , is on the order of ξ_F and D is the diffusion constant. When the energy gap is smaller than E_{ex} and the Thouless energy $E_{Th} = \hbar D/d_F^2$, as in the experiment described below, the energy dependence of $Q(\epsilon)$ is basically fixed by the BCS superconducting density of states. Therefore, the spectral current density is peaked at the superconducting energy gap. It is either positive or negative for $E_{ex} < 9\pi^2/16E_{Th}$ (i.e. $d_F < 3\pi/4\xi_F$) or $E_{ex} > 9\pi^2/16E_{Th}$ (i.e. $d_F > 3\pi/4\xi_F$) respectively as shown in Fig. 1. The critical current I_c at zero temperature is obtained by integrating $Q(\epsilon)$; for $d_F/\xi_F >> 1$, $I_c = 3.21\Delta/R_n \left[d_F/\xi_F \right] \exp \left[-d_F/\xi_F \right] \sin \left[\pi/4 + d_F/\xi_F \right]$ as found by Buzdin [12]. Thus, we recover quantitatively the behavior illustrated above.

Experimentally, since the coherence length in F is very small ($\xi_F \simeq 30$ Å, as shown below) the simplest way to measure the critical current is to fabricate planar junctions where a thin insulating barrier is inserted between the superconducting counterelectrode and the ferromagnet. The tunnel barrier raises the junction resistance, R_n , lowering I_c to measurable values (typically 10-100 μA). In a Superconductor/Insulator/Ferromagnet/Superconductor (SIFS) Josephson junction the energy spectrum of the Andreev bound states in F is modified by the insulating layer [13]. However, the current spectral density reported in Fig. 1 shows the same general behavior as observed in SFS junctions, including the change of sign of the Josephson critical current as a function of the ferromagnetic layer thickness.

Planar $Nb/Al/Al_2O_3/PdNi/Nb$ junctions were fabricated by e-gun thin film evaporation in a typical base pressure of 10^{-9} Torr, rising to 10^{-8} Torr during deposition. The film thickness was monitored during growth to better than 1 Å by a quartz balance. The junction had the standard four terminal cross-geometry [4], defined during evaporation by shadow masks. A Si wafer was first covered by 500 Å of SiO. Then, a 1500 Å thick Nb strip was evaporated and backed by 500 Å of Al. The critical temperature of the Nb strip was 9.2 K and its residual-resistance-ratio ratio about 4. The Al surface oxidation was performed in a glow discharge during 1 min. and completed in a 10 Torr oxygen atmosphere during 2 min. A square window of $1mm \times 1mm$ left in a 500 Å thick SiO layer deposited on the Al defined the junction area. Eight junctions were aligned on the same Nb/Al strip. A PdNi strip (thickness 40-150 Å) perpendicular to the Nb/Al strip was then evaporated on each junc-

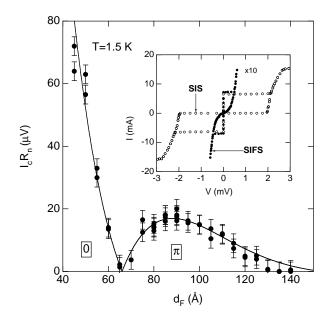


FIG. 2: Josephson coupling as a function of thickness of the PdNi layer (full circles). The critical current cancels out at $d_F \simeq 65$ Å indicating the transition from "0" to " π "-coupling. The full line is the best fit obtained from the theory (eqn.(1)) as described in the text. Inset shows typical I-V characteristics of two junctions with (full circles), and without (empty circles) PdNi layer.

tion and covered by a 500 Å thick Nb counter-electrode $(T_c=8.7~{\rm K})$. The junction resistance varied from 50 $m\Omega$ to 400 $m\Omega$. The entire process was carried out without breaking the vacuum in the deposition chamber. The Ni concentration was about 12 % as checked by Rutherford Backscattering Spectrometry on samples evaporated at the same time. At this concentration, the PdNi is an itinerant ferromagnet [14], whose the Curie temperature is about 100 K. The junction was polarized by an ac current, the I-V characteristics being monitored on a digital commercial oscilloscope set in the X-Y mode and directly recorded from the oscilloscope. Measurements were performed down to 1.5 K; the minimum detectable value of I_c was about 1 μA . A μ -metal shield reduced the residual magnetic field on the sample to 10^{-2} Gauss.

The $Nb/Al/Al_2O_3/Nb$ junctions without a ferromagnetic layer showed high quality tunneling. At low temperature the Nb/Al bilayer is a homogeneous superconductor. The I-V characteristic is hysteretic as expected for SIS junctions [15]. The subgap conductance at 1.5 K is only 10^{-4} of the high energy conductance corresponding to negligible current leakage as shown in the inset of Fig. 2. The I_cR_n product is 1.25 mV with junction to junction fluctuations of at most 15 %. The inset of Fig. 2 also shows the I-V characteristics of a Nb/Al/Al₂O₃/PdNi/Nb junction with a thin layer of PdNi ($d_F = 50$ Å). The critical current is strongly reduced while the subgap conductance is enhanced. Both

effects result from the suppression of the order parameter in F by the exchange field. The superconducting correlations are so efficiently reduced at the Al/Al₂O₃/PdNi interface [4] that the dissipative branch of the I-V curve reflects the energy dependence of the density of states in the Nb/Al bilayer.

The Josephson coupling, I_cR_n , as a function of the thickness of the ferromagnetic layer is presented in the main body of Fig. 2. We chose this representation to eliminate fluctuations in the critical current that are simply due to fluctuations in the junction resistance. For each value of d_F , the I_cR_n product of two different junctions is reported, with typical sample to sample variations of less than 10 %, illustrating the reproducibility of the junction fabrication technique. The Josephson coupling is of the order of 10-20 μV , i.e. 100 times lower that that measured on junctions without PdNi. The sign of I_c cannot be determined from the I-V characteristics and the transition from "0" to " π " coupling is revealed as a zero of the $I_c R_n$ product. The latter occurs at $d_F \simeq 65$ Å, consistent with our recent measurements of the density of states in F [4]. Fig. 2 also shows the best fit to the theory in which the I_cR_n product is obtained by integrating the spectral current density found solving the Usadel equations for a SIFS junction (see Fig. 1):

$$I_c R_n = \frac{\pi}{2} \frac{\Delta}{e} \frac{1}{\gamma_b} \frac{\cos\frac{d_F}{\xi_F} \cosh\frac{d_F}{\xi_F} + \sin\frac{d_F}{\xi_F} \sinh\frac{d_F}{\xi_F}}{\cos^2\frac{d_F}{\xi_F} \cosh^2\frac{d_F}{\xi_F} + \sin^2\frac{d_F}{\xi_F} \sinh^2\frac{d_F}{\xi_F}}$$
(1)

where γ_b is the PdNi/Nb interface resistance. The Josephson coupling decreases linearly with γ_b as do the number of Andreev reflections at the S/F interface [16]. The fitting parameters are $\gamma_b=5.3$ and $\xi_F=28\text{Å}$. The interface resistance is the same as that deduced from the thickness dependence of the zero energy density of states [4], while the coherence length in PdNi is smaller possibly because of the few per cent increase in the Ni concentration. The corresponding exchange energy is $E_{ex}=35meV$, taking $v_F=2\times10^7cm/s$ and the mean free path in the PdNi equal to d_F as found by resistivity measurements on bare PdNi thin films.

In Fig. 3 the critical current, I_c as a function of the magnetic flux is presented for (i) a junction without PdNi and (ii) three junctions with different thickness of PdNi but roughly the same I_cR_n product. One of the latter gives "0" coupling (60 Å) and two " π " coupling (90 Å and 110 Å). The diffraction patterns are those expected for a square junction with homogeneous current density [15] provided a small misorientation of 7° between the field direction and one edge of the junction is included (see fit in Fig. 3). The critical current cancels out when an integer of flux quanta settles into the junction. As the field penetrates in a volume whose cross-section is given by $w(2\lambda + d_F)$, where λ is the penetration depth and w=1 mm the junction width, an estimate of λ for H=0.2

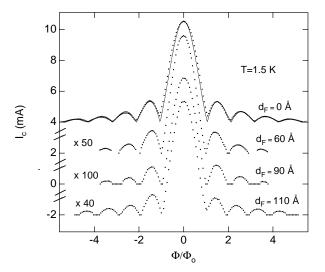


FIG. 3: Critical current as a function of magnetic flux for four different junctions, three with and one without PdNi. The data are shifted vertically for clarity. The full line is the Fraunhofer pattern expected for a square junction with homogeneous current density and a misalignment of 7° between the field and the junction edge. The junctions with PdNi have about the same coupling. The diffraction patterns are not affected by the PdNi magnetization.

Gauss corresponding to the first quantum flux, is λ =500 Å, consistent with the value expected for Nb thin films [15]. Importantly, the maximum critical current occurs at zero applied field independently of the ferromagnetic layer thickness. This shows that the Josephson coupling presented in Fig. 2 is indeed the maximum coupling as assumed. It also indicates that the field produced by the thin PdNi film falls off rapidly in the superconductor when one moves away from the S/F interface. Therefore no orbital dephasing is generated in S by the ferromagnetic layer which acts only through the spin degree of freedom as expected in the Pauli limit [17].

The temperature dependence of the critical current is found by integrating the spectral current density, $Q(\epsilon)$ multiplied by the distribution function [9]. Far from $d_F \simeq 3\pi/4\xi_F$, where the critical current cancels out, I_c is mainly determined by the temperature dependence of the density of states on each side of the junction. As the energy dependence of the density of states in the Al and PdNi is not exactly the BCS density of states, the temperature dependence of I_c shows a more linear behavior [18] than that originally found by Ambegaokar-Baratoff [19] for two bulk superconductors separated by a tunnel barrier. This linear behavior is shown in Fig. 4 where the temperature dependence of the normalized critical current for three junctions with different PdNi thickness is reported ($d_F = 50\text{Å}$ for "0" coupling, $d_F = 80\text{Å}$ for " π " coupling and $d_F = 70$ Å near the transition). The critical current of the junction with a 70Å thick PdNi layer is too small to be measured at T > 5K.

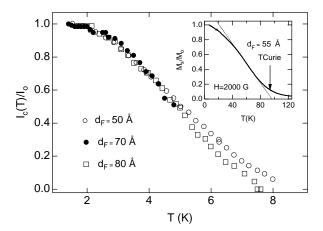


FIG. 4: Normalized temperature dependence of the critical current for three different PdNi thicknesses. Note linear dependence expected for Superconductor-Insulator-Normal-Superconductor tunnel junction 18. Inset shows normalized saturation magnetization as a function of temperature, measured via anomalous Hall effect for a bare PdNi thin film.

When $d_F \simeq 3\pi/4\xi_F$, where the critical current cancels, the spectral current density $Q(\epsilon)$, changes sign as a function of energy. Thus, changing the occupation of the ABS by raising the temperature allows to shift the spectral weight from a positive to a negative current density or equivalently from forward to back-ward ABS. This results in a temperature induced "0-junction"-" π junction" transition as recently observed in SFS junctions [20]. Such a transition only occurs for junctions very close to the critical point and it requires a I_cR_n product lower than $1\mu V$. Because of their much smaller junction resistance, SFS junctions are more suitable than SIFS to investigate small Josephson coupling. In fact, the minimum I_cR_n product measurable in our junctions is as low as a few μV and hence too large to reveal a sign change. As a final check we measured the temperature dependence of the saturation magnetization of bare PdNi thin films $(d_F=40\text{-}150 \text{ Å})$ via the anomalous Hall effect [21]. As shown in the inset of Fig. 4 for $d_F = 55$ Å the normalized saturation magnetization, M_s/M_0 , which is proportional to the Hall signal at H=2000 Gauss, shows very small variations at low temperature (T < 10 K) corresponding to a few per cent change in M_s . Thus the long range magnetic order at low temperature is well defined and the small change in M_s has negligible effects on the critical current temperature dependence.

In summary, we have shown that the critical current of SIFS Josephson junction is an oscillating function of the thickness of the ferromagnetic layer. The zero of the critical current obtained for $d_F \simeq 3\pi/4\xi_F$ indicates

a change of sign of I_c , leading to " π -coupling". This is a consequence of the superconducting order parameter oscillations induced in the ferromagnet by the proximity effect as recently observed by tunneling spectroscopy [4]. Such ferromagnetic-based " π -junctions" may represent a new element in the architecture of novel quantum devices as recently suggested [22].

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